## NSN 5961-01-281-2932

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-281-2932 **Inclosure Material:** Metal and ceramic **Overall Length:** 2.612 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case **Overall Width Across Flats:** 1.056 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 forward voltage, peak **Current Rating Per Characteristic:** 110.00 amperes forward current, average of standard range **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector universal and 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No